- Equivalent Input Noise Voltage 3.5 nV/√Hz
- Unity-Gain Bandwidth . . . 10 MHz Typ
- Common-Mode Rejection Ratio 100 dB Typ
- High DC Voltage Gain . . . 100 V/mV Typ
- Peak-to-Peak Output Voltage Swing
 32 V Typ With V_{CC+} = ±18 V and R_L = 600 Ω
- High Slew Rate . . . 13 V/μs Typ
- Wide Supply Voltage Range ±3 V to ±20 V
- Low Harmonic Distortion
- Designed to Be Interchangeable With Signetics NE5534, NE5534A, SE5534, and SE5534A

description

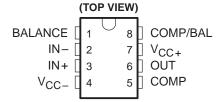
The NE5534, NE5534A, SE5534, and SE5534A are monolithic high-performance operational amplifiers combining excellent dc and ac characteristics. Some of the features include very low noise, high output drive capability, high unitygain and maximum-output-swing bandwidths, low distortion, and high slew rate.

These operational amplifiers are internally compensated for a gain equal to or greater than three. Optimization of the frequency response for various applications can be obtained by use of an external compensation capacitor between COMP and COMP/BAL. The devices feature input-protection diodes, output short-circuit protection, and offset-voltage nulling capability.

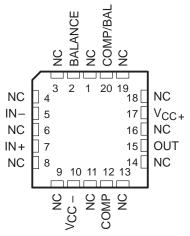
For the NE5534A, a maximum limit is specified for equivalent input noise voltage.

The NE5534 and NE5534A are characterized for operation from 0°C to 70°C. The SE5534 and SE5534A are characterized for operation over the full military temperature range of – 55°C to 125°C.

NE5534, NE5534A . . . D OR P PACKAGE SE5534, SE5534A . . . JG PACKAGE

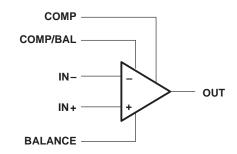


SE5534, SE5534A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

symbol



SE5534A FROM TI NOT RECOMMENDED FOR NEW DESIGNS

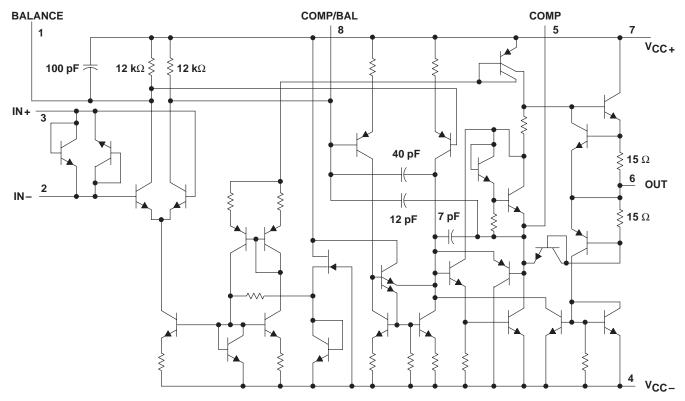
AVAILABLE OPTIONS

	Via may				
TA	V _{IO} max AT 25°C	SMALL OUTLINE (D)	CERAMIC (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)
0°C to 70°C	4 mV	NE5534D NE5534AD	_ _	_ _	NE5534P NE5534AP
– 55°C to 125°C	2 mV	_	SE5534FK SE5534AFK	SE5534JG SE5534AJG	_

The D package is available taped and reeled. Add the suffix R to the device type (e.g., NE5534DR).

SLOS070 – JULY 1979 – REVISED SEPTEMBER 1990

schematic



All component values shown are nominal.

Pin numbers shown are for D, JG, and P packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC+} (see Note 1)
Supply voltage, V _{CC} (see Note 1)
Input voltage either input (see Notes 1 and 2)
Input current (see Note 3) ±10 mA
Duration of output short circuit (see Note 4) unlimited
Continuous total power dissipation See Dissipation Rating Table
Operating free-air temperature range: NE5534, NE5534A
SE5534, SE5534A – 55°C to 125°C
Storage temperature range – 65°C to 150°C
Case temperature for 60 seconds: FK package
Lead temperature range 1,6 mm (1/16 inch) from case for 60 seconds: JG package
Lead temperature range 1,6 mm (1/16 inch) from case for 10 seconds: D or P package 260°C

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 - 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
 - 3. Excessive current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs unless some limiting resistance is used.
 - 4. The output may be shorted to ground or to either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.



SLOS070 - JULY 1979 - REVISED SEPTEMBER 1990

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \le 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	N/A
FK (see Note 5)	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	N/A

NOTE 5: For the FK package, power rating and derating factor will vary with actual mounting technique used. The values stated here are believed to be conservative.

recommended operating conditions

	MIN	NOM MAX	UNIT
Supply voltage, V _{CC+}	5	15	V
Supply voltage, V _{CC} _	- 5	– 15	V

electrical characteristics, V_{CC} \pm = ± 15 V, T_A = $25^{\circ}C$ (unless otherwise noted)

PARAMETER				NE553	34, NE5	534A	SE553	UNIT		
	PARAMETER	TEST COND	OITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNII
V _{IO}	Input offset voltage	$V_0 = 0,$	T _A = 25°C		0.5	4		0.5	2	mV
۷IO	input onset voitage	$R_S = 50 \Omega$	T _A = Full range			5		3	IIIV	
lio	Input offset current	V _O = 0	T _A = 25°C		20	300		10	200	nA
טוי	input onset current	VO = 0	T _A = Full range			400			500	
I _{IB}	Input bias current	V _O = 0	T _A = 25°C		500	1500		400	800	nA
אוי	input bias current	VO = 0	T _A = Full range			2000			1500	ш
VICR	Common-mode input voltage range			±12	±13		±12	±13		٧
V (())	Maximum peak-to-peak	P. > 600 O	$V_{CC\pm} = \pm 15 \text{ V}$	24	26		24	26		V
VO(PP)	output voltage swing	R _L ≥ 600 Ω	V _{CC±} = ±18 V	30	32		30	32		V
Δ. σ	Large-signal differential	$V_0 = \pm 10 \text{ V},$	T _A = 25°C	25	100		50	100		V/mV
AVD	voltage amplification	R _L ≥ 600 Ω	T _A = Full range	15			25			V/IIIV
Small-signal differential		f = 10 kHz	$C_C = 0$		6			6		V/mV
A _{vd}	voltage amplification	T = TO KITZ	$C_C = 22 pF$		2.2			2.2		V/111V
		$V_0 = \pm 10 \text{ V},$	CC = 0		200			200		
ВОМ	Maximum-output-swing	$V_0 = \pm 10 \text{ V},$	$C_C = 22 pF$		95			95		kHz
DOM	bandwidth	$V_{CC\pm} = \pm 18 \text{ V},$ $R_L \ge 600 \Omega,$	$V_O = \pm 14 \text{ V},$ $C_C = 22 \text{ pF}$		70			70		KI IZ
B ₁	Unity-gain bandwidth	$C_C = 22 \text{ pF},$	C _L = 100 pF		10			10		MHz
rį	Input resistance			30	100		50	100		kΩ
z _O	Output impedance	$A_{VD} = 30 \text{ dB},$ $C_{C} = 22 \text{ pF},$	$R_L \ge 600 \Omega$, f = 10 kHz		0.3			0.3		Ω
CMRR	Common-mode rejection ratio	$V_O = 0$, $R_S = 50 \Omega$	V _{IC} = V _{ICR} min,	70	100		80	100		dB
ksvr	Supply voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$V_{CC+}=\pm 9 V \text{ to} \pm 15 V,$ $V_{O}=0,$	R _S = 50 Ω	80	100		86	100		dB
los	Output short-circuit current				38			38		mA
loo	Supply current	$V_{O} = 0,$	T _A = 25°C		4	8		4	6.5	mA
ICC		No load	T _A = Full range						9	111/

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range is T_A = 0°C to 70°C for NE5534 and NE5534A and – 55°C to 125°C for SE5534 and SE5534A.



NE5534, NE5534A, SE5534, SE5534A LOW-NOISE OPERATIONAL AMPLIFIERS

SLOS070 - JULY 1979 - REVISED SEPTEMBER 1990

operating characteristics, $V_{CC}\,\pm$ = ± 15 V, T_A = $25^{\circ}C$

PARAMETER		TEST	CONDITIONS	SE55	SE5534, NE5534		SE5534A, NE5534A			UNIT	
		IEST	CONDITIONS	MIN TYP MAX		MIN	TYP	MAX	0.411		
SR	CD Clauserta at units nain		C _C = 0		13		13			V/μs	
SIX	Slew rate at unity gain	$C_C = 22 pF$			6			6		ν/μδ	
t _r	Rise time	$V_{I} = 50 \text{ mV},$	$A_{VD} = 1$, $C_{C} = 22 pF$,		20			20		ns	
	Overshoot factor	$R_L = 600 \Omega,$ $C_L = 100 pF$		20%							
t _r	Rise time	$V_{I} = 50 \text{ mV},$	$A_{VD} = 1$, $C_{C} = 47 \text{ pF}$,		50		50			ns	
	Overshoot factor	$R_L = 600 \Omega,$ $C_L = 500 pF$		ου = 47 ρι,		35%			35%		
\ <u></u>	Equivalent input poice voltage	f = 30 Hz			7			5.5	7	->44/15	
Vn	Equivalent input noise voltage	f = 1 kHz			4			3.5	4.5	nV/√Hz	
	Equivalent input poice current	f = 30 Hz			2.5			1.5		- A (/ L	
^I n	Equivalent input noise current	f = 1 kHz			0.6			0.4		pA/√Hz	
F	Average noise figure	$R_S = 5 k\Omega$,	f = 10 Hz to 20 kHz					0.9		dB	

TYPICAL CHARACTERISTICS[†]

NORMALIZED INPUT BIAS CURRENT AND INPUT OFFSET CURRENT

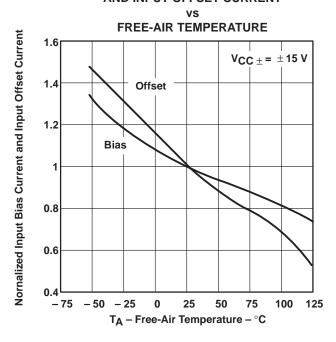


Figure 1

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE

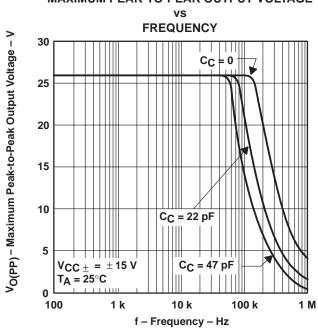


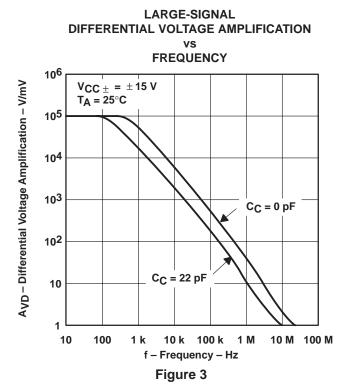
Figure 2

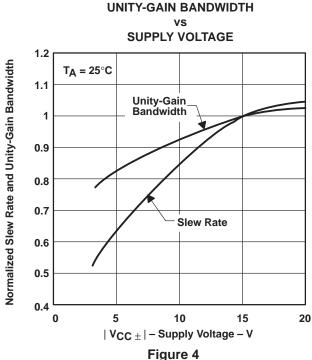
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



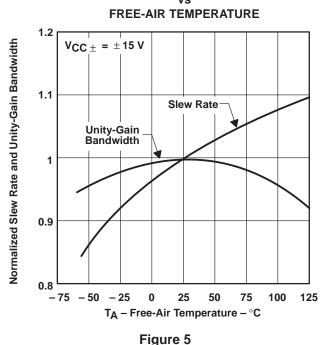
NORMALIZED SLEW RATE AND

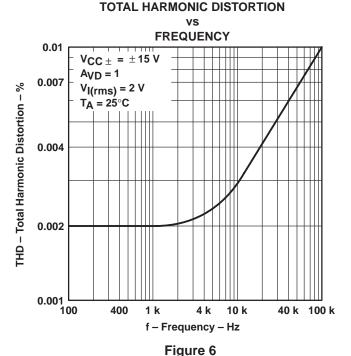
TYPICAL CHARACTERISTICS†





NORMALIZED SLEW RATE AND UNITY-GAIN BANDWIDTH





† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

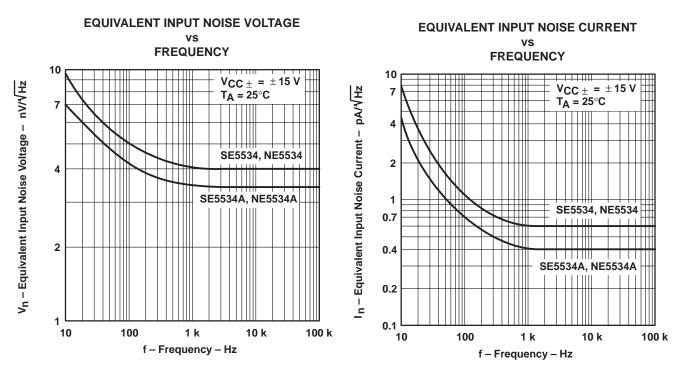
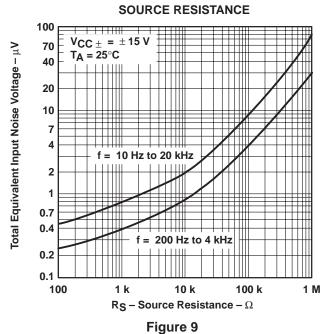


Figure 7 Figure 8

TOTAL EQUIVALENT INPUT NOISE VOLTAGE vs



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PRODUCT FOLDER | PRODUCT INFO: FEATURES | DESCRIPTION | DATASHEETS |
PRICING/AVAILABILITY | APPLICATION NOTES |
USER MANUALS

PRODUCT SUPPORT: <u>DEVELOPMENT TOOLS</u> | <u>APPLICATIONS</u>

SE5534, Low-Noise Operational

DEVICE STATUS: ACTIVE

FEATURES <u>Back to Top</u>

Equivalent Input Noise Voltage
 3.5 nV/ √ (Hz)\

- Unity-Gain Bandwidth...10 MHz Typ
- Common-Mode Rejection Ratio 100 dB Typ
- High DC Voltage Gain...100 V/mV Typ
- Peak-to-Peak Output Voltage Swing 32 V Typ With V $_{\rm CC\pm}$ = ± 18 V and R $_{\rm L}$ = 600 Ω
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DESCRIPTION Back to Top

The NE5534, NE5534A, SE5534, and SE5534A are monolithic high-performance operational amplifiers combining excellent dc and ac characteristics. Some of the features include very low noise, high output drive capability, high unity-

gain and maximum-output-swing bandwidths, low distortion, and high slew rate.

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For the NE5534A, a maximum limit is specified for equivalent input noise voltage.

The NE5534 and NE5534A are characterized for operation from 0°C to 70°C. The SE5534 and

2 of 3

SE5534A are characterized for operation over the full military temperature range of - 55°C to 125°C.

The D package is available taped and reeled. Add the suffix R to the device type (e.g., NE5534DR).

TECHNICAL DOCUMENTS

Back to Top

To view the following documents, Acrobat Reader 3.x is required.

To download a document to your hard drive, right-click on the link and choose 'Save'.

DATASHEET Back to Top

Full datasheet in Acrobat PDF: slos070.pdf (119 KB) (Updated: 09/01/1990)

Full datasheet in Zipped PostScript: slos070.psz (109 KB)

APPLICATION NOTES

Back to Top

View Application Reports for Signal Amplifiers (Less than equal to 100MHz)

- Analog Applications Journal May 2000 (SLYT015 Updated: 04/20/2000)
- Analog Applications Journal, September 1999 edition (SLYT005 Updated: 07/15/1999)
- Analysis Of The Sallen-Key Architecture (SLOA024A Updated: 07/27/1999)

USER MANUALS <u>Back to Top</u>

- Universal Op Amp Single, Dual, Quad (SOIC) Evaluation Module With Shutdown (SLOU061, 1160 KB - Updated: 10/22/1999)
- Universal Operational Amplifier EVM (SLVU006A, 387 KB Updated: 03/22/1999)
- <u>Universal Operational Amplifier Evaluation Module Selection Guide</u> (SLOU060A, 16 KB Updated: 09/28/2000)
- Universal Operational Amplifier Single, Dual, Quad (MSOP/TSSOP) (SLOU055, 1196 KB Updated: 10/22/1999)
- Universal Operational Amplifier Single, Dual, Quad (PDIP) (SLOU062, 1211 KB Updated: 10/22/1999)

PRICING/AVAILABILITY

■Back to Top

ORDERABLE DEVICE	<u>PACKAGE</u>	<u>PINS</u>	TEMP (°C)	<u>STATUS</u>	BUDGETARY PRICE US\$/UNIT OTY=1000+	PACK QTY	DSCC NUMBER	PRICING/AVAILABILITY
SE5534FKB	<u>FK</u>	20	-55 TO 125	ACTIVE	11.15	1		Check stock or order
SE5534JG	<u>JG</u>	8	-55 TO 125	ACTIVE	4.22	1		Check stock or order
SE5534JGB	<u>JG</u>	8	-55 TO 125	ACTIVE	4.95	1		Check stock or order

DEVELOPMENT TOOLS

Back to Top

Tool Part Number	Tool Title	Tool Type
	Universal EVM for Single/Dual OpAmps without Shutdown in MSOP/SOIC/SOT-23 packages	Evaluation Modules (EVM)
UNIV-OPAMP-	Universal EVM for Single/Dual OpAmps with Shutdown in	Evaluation Modules

3 of 3

<u>2B</u>	MSOP/SOIC/SOT-23 packages	(EVM)
UNIV-OPAMP- 3B	Universal EVM for Single/Dual/Quad OpAmps with/without Shutdown in MSOP/TSSOP packages	Evaluation Modules (EVM)
<u>UNIV-OPAMP-</u> 4B	Universal EVM for Single/Dual/Quad OpAmps with/without Shutdown in SOIC packages	Evaluation Modules (EVM)
UNIV-OPAMP- 5B	Universal EVM for Single/Dual/Quad OpAmps with/without Shutdown in PDIP packages	Evaluation Modules (EVM)

Table Data Updated on: 11/12/2000

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